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** CONTINUING DATA *****

This application is a DIV of 10/261,487 10/02/2002 PAT 6,756,611 *TD*
which is a DIV of 09/986,332 11/08/2001 *TD*
which is a CON of 09/603,437 06/23/2000 ABN *TD*
which is a DIV of 09/202,141 12/09/1998 PAT 6,153,010 *TD*
which is a 371 of PCT/JP98/01640 04/09/1998 *TD*

** FOREIGN APPLICATIONS *****

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35 USC 119 (a-d) conditions met	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance				
Verified and Acknowledged Examiner's Signature <i>TD</i>	Initials <i>TD</i>	JAPAN	DRAWING 8	CLAIMS 27	CLAIMS 2

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TITLE
Nitride semiconductor growth method, nitride semiconductor substrate and nitride semiconductor device